Interesting Numbers

{single,double}

Description	e <u>xp</u>	frac	Numeric Value
Zero	0000	0000	0.0
Smallest Pos. <u>Denorm</u> .	0000	0001	$2^{-\{23,52\}} \times 2^{-\{126,1022\}}$
Single ≈ 1.4 x 10 ⁻⁴⁵			
■ Double $\approx 4.9 \times 10^{-324}$			
Largest <u>Denormalized</u>	0000	1111	$(1.0 - \varepsilon) \times 2^{-\{126,1022\}}$
■ Single $\approx 1.18 \times 10^{-38}$			
■ Double $\approx 2.2 \times 10^{-308}$			
Smallest Pos. Normalized	0001	0000	1.0 x $2^{-\{126,1022\}}$
Just larger than largest denor	malized		
One	0111	0000	1.0
Largest Normalized	1110	1111	$(2.0 - \varepsilon) \times 2^{\{127,1023\}}$
Single ≈ 3.4 x 10 ³⁸			

bwlq 1248 8 16 32 64 char short int long long movzbl

■ Double $\approx 1.8 \times 10^{308}$

Type	Form	Operand value	Name
Immediate	\$Imm	Imm	Immediate
Register	r_a	$R[r_a]$	Register
Memory	Imm	M[Imm]	Absolute
Memory	(r_a)	$M[R[r_a]]$	Indirect
Memory	$Imm(\mathbf{r}_b)$	$M[Imm + R[r_b]]$	Base + displacement
Memory	$(\mathbf{r}_b,\mathbf{r}_i)$	$M[R[r_b] + R[r_i]]$	Indexed
Memory	$Imm(\mathbf{r}_b,\mathbf{r}_i)$	$M[Imm + R[r_b] + R[r_i]]$	Indexed
Memory	$(\mathbf{r}_i, \mathbf{s})$	$M[R[r_i] \cdot s]$	Scaled indexed
Memory	$Imm(,r_i,s)$	$M[Imm + R[r_i] \cdot s]$	Scaled indexed
Memory	$(\mathbf{r}_b, \mathbf{r}_i, s)$	$M[R[r_b] + R[r_i] \cdot s]$	Scaled indexed
Memory	$Imm(\mathbf{r}_b,\mathbf{r}_i,s)$	$M[Imm + R[r_b] + R[r_i] \cdot s]$	Scaled indexed

63	31	15	7 0	1
%rax	%eax	%ax	%al	Return value
%rbx	%ebx	%bx	%bl	Callee saved
%rcx	%ecx	%cx	%cl	4th argument
%rdx	%edx	%dx	%d1	3rd argument
%rsi	%esi	%si	%sil	2nd argument
%rdi	%edi	%di	%dil	1st argument
%rbp	%ebp	%bp	%bpl	Callee saved
%rsp	%esp	%sp	%spl	Stack pointer
%r8	%r8d	%r8w	%r8b	5th argument
%r9	%r9d	%r9w	%r9b	6th argument
%r10	%r10d	%r10w	%r10b	Caller saved
%r11	%r11d	%r11w	%r11b	Caller saved
%r12	%r12d	%r12w	%r12b	Callee saved
%r13	%r13d	%r13w	%r13b	Callee saved
%r14	%r14d	%r14w	%r14b	Callee saved
%r15	%r15d	%r15w	%r15b	Callee saved

SetX	Condition	Description
sete	ZF	Equal / Zero
setne	~ZF	Not Equal / Not Zero
sets	SF	Negative
setns	~SF	Nonnegative
setg	~ (SF^OF) &~ZF	Greater (Signed)
setge	~ (SF^OF)	Greater or Equal (Signed)
setl	(SF^OF)	Less (Signed)
setle	(SF^OF) ZF	Less or Equal (Signed)
seta	~CF&~ZF	Above (unsigned)
setb	CF	Below (unsigned)

Format	Computation		
addq	Src,Dest	Dest = Dest + Src	
subq	Src,Dest	Dest = Dest - Src	
imulq	Src,Dest	Dest = Dest * Src	
salq	Src,Dest	Dest = Dest << Src	
sarq	Src,Dest	Dest = Dest >> Src	
shrq	Src,Dest	Dest = Dest >> Src	
xorq	Src,Dest	Dest = Dest ^ Src	
andq	Src,Dest	Dest = Dest & Src	
orq	Src,Dest	Dest = Dest Src	

incq DestDest = Dest + 1decq DestDest = Dest - 1negq DestDest = - Destnotq DestDest = \sim Dest

Address Computation Instruction

■ leaq Src, Dst

- Src is address mode expression
- Set <u>Dst</u> to address denoted by expression

Uses

- Computing addresses without a memory reference
 - E.g., translation of p = &x[i];
- Computing arithmetic expressions of the form x + k*y
 - k = 1, 2, 4, or 8

Example

```
long m12(long x)
{
  return x*12;
}
```

Converted to ASM by compiler:

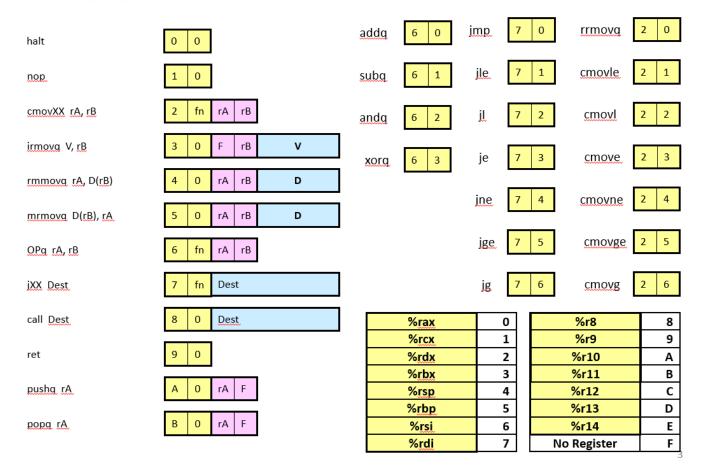
```
leaq (%rdi,%rdi,2), %rax # t <- x+x*2
salq $2, %rax # return t<<2</pre>
```

cmp a,b b-a
test a,b a&b

jХ	Condition	Description
jmp	1	Unconditional
je	ZF	Equal / Zero
jne	~ZF	Not Equal / Not Zero
js	SF	Negative
jns	~SF	Nonnegative
jg	~ (SF^OF) &~ZF	Greater (Signed)
jge	~ (SF^OF)	Greater or Equal (Signed)
jl	(SF^OF)	Less (Signed)
jle	(SF^OF) ZF	Less or Equal (Signed)
ja	~CF&~ZF	Above (unsigned)
jb	CF	Below (unsigned)

4

Y86-64 instruction set



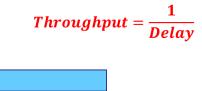
弄反 分成 n 块,每块是 max ps = $10^{-12}ps$ IPS MIPS /1e6

Pipeline Diagrams

Time

Unpipelined

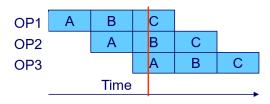
OP1 OP2 OP3





■ Cannot start new instruction until previous one completes

3-Way Pipelined



$$Throughput = \frac{1}{Delay} \times N$$

■ Up to 3 instructions running simultaneously

- 33 -

Latency 一个的长度 delay n 个的长度

throughput = n/delay = 1 / latency

Nonvolatile Memories

DRAM and SRAM are volatile memories

Lose information if powered off

- 5 3
- Nonvolatile memories retain value even if powered off
 - Read-only memory (ROM): programmed during production
 - Programmable ROM (PROM): can be programmed once
 - Erasable PROM (EPROM): can be erased 1000 times
 - Electrically <u>eraseable</u> PROM (EEPROM): can be erased 100,000 times
 - Flash memory: EEPROMs. with partial (block-level) erase capability
- Uses for Nonvolatile Memories
 - Firmware programs stored in a ROM (BIOS, controllers for disks, network cards, graphics accelerators, security subsystems,...)
 - Solid state disks (thumb drives, smart phones, mp3 players, tablets, laptops,...)
 - Disk caches

vant and O'Hallaron. Computer Systems: A Programmer's Perspective. Third Edition

A Disk Drive

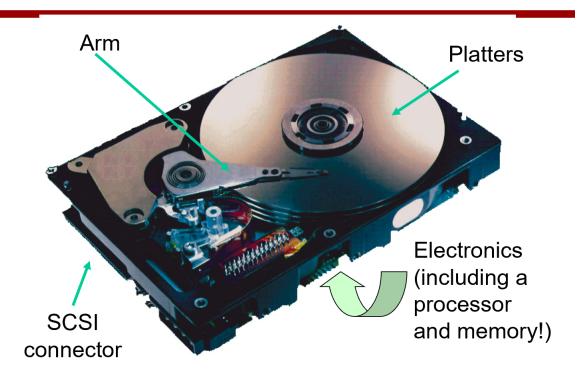


Image courtesy of Seagate Technology

硬盘有很多 Platter (拼盘),每个盘有两个面 (Surface),每个面分成若干 tracks (圆环),分成若干段 (sectors)

Disk controller 控制

DMA Direct Memory Acess, Disk \rightarrow Main Memory

Hit: 已经在 cache

miss: 不在

算地址记得*一个元素的byte数 (4)

FIFO

LRU: 每次在 cache 里拖到最后

Pasted image 20240319125748.png

同步异常 Traps 故意可恢复, Faults 不故意可以恢复, Aborts 不故意不可恢复

Pasted image 20240327140256.png

```
fork()
exit()
wait() 收割reaping
waitpid()
getpid()
getppid()
```

Pasted image 20240326131005.png

N (virtual, disk) > M (physical, dram)

共享偏移量

page table

page hit: 在 m (physical memory / dram 里)

换一个驱逐然后 page hit

如果工作集>主内存爆了

PTE (page table entries)

MMU (Memory management unit)

Page table base register (PTBR)

VPN PPN (Viertual Physical page number / offset)

TLBI TLBT.

Lec11

Pasted image 20240409130329.png 父子共享一个(描述符)但是同一个程序多个是并行